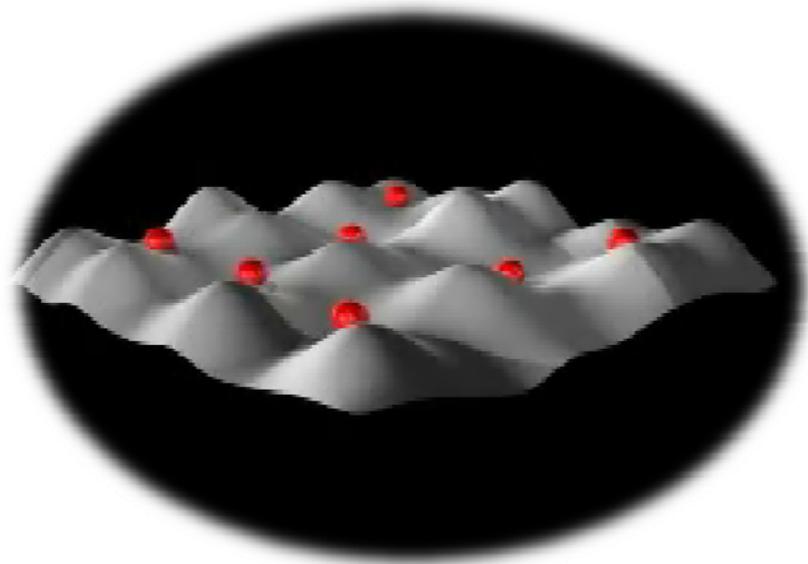


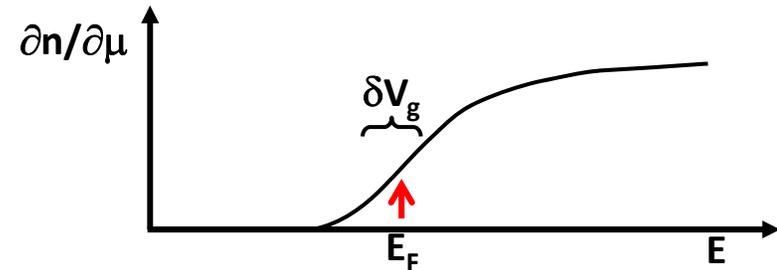
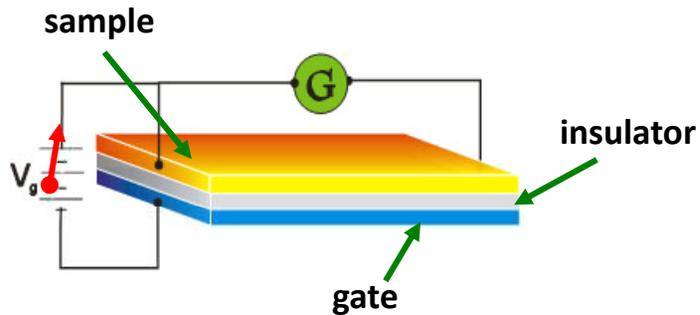
# Disorder vs. Interaction in open Quantum Systems



## Anderson-Insulator

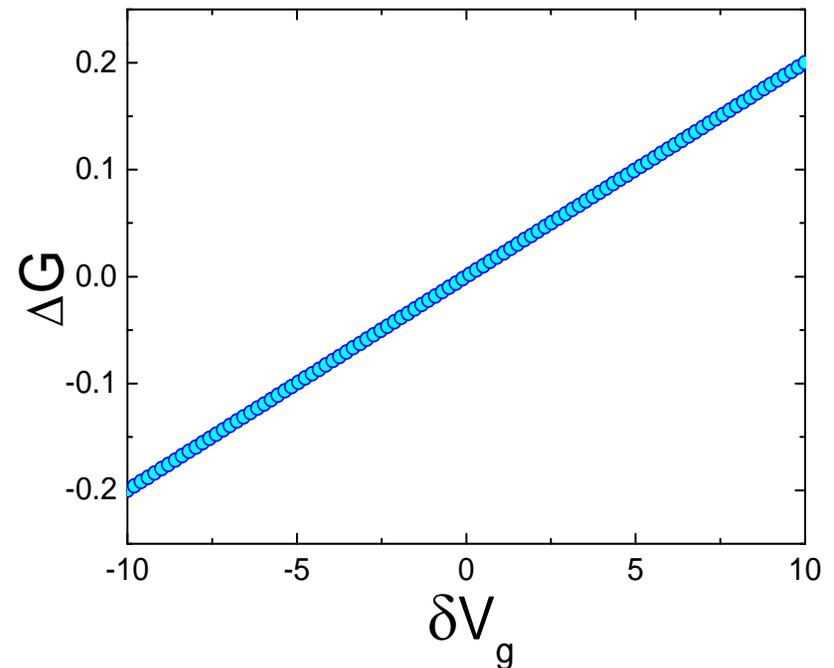
...the natural test-bed for Disorder-Interactions effects

# ...the field-effect technique:



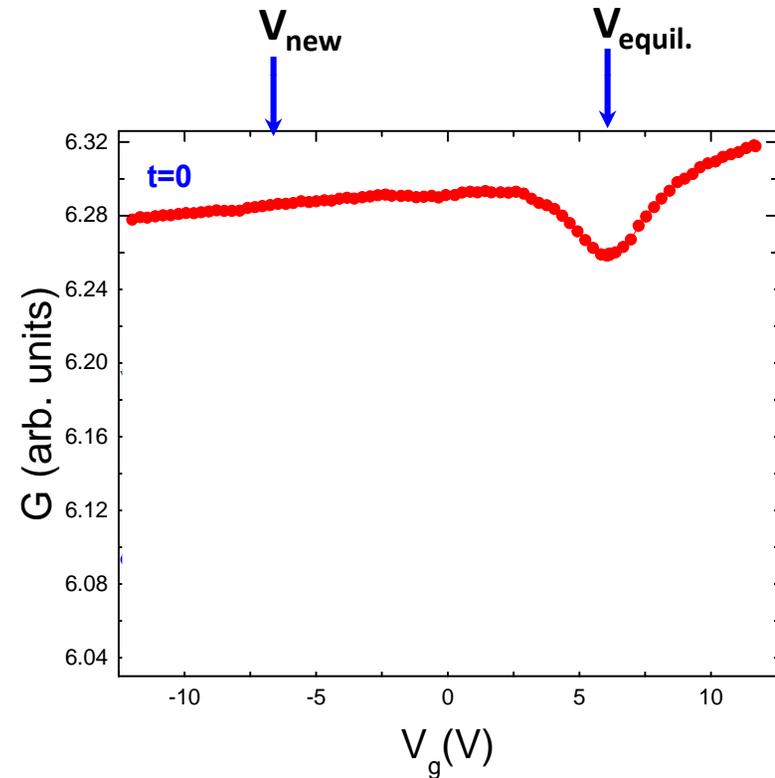
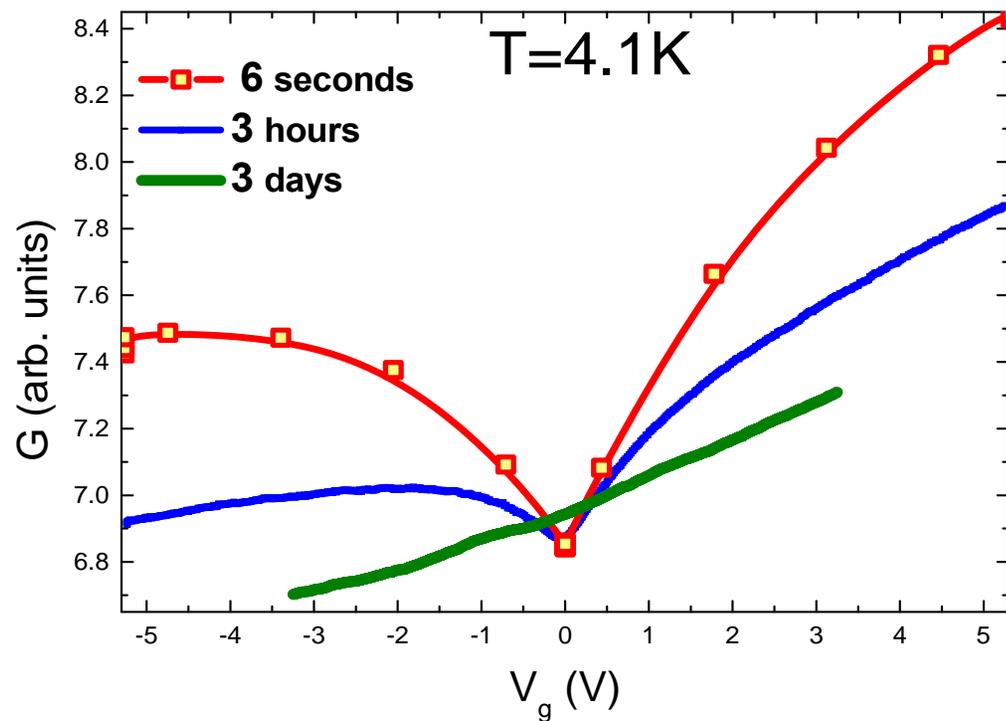
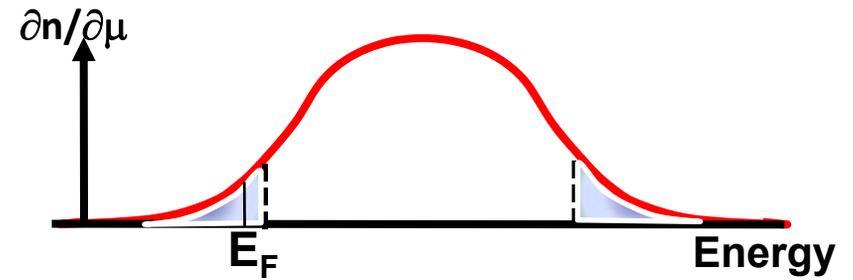
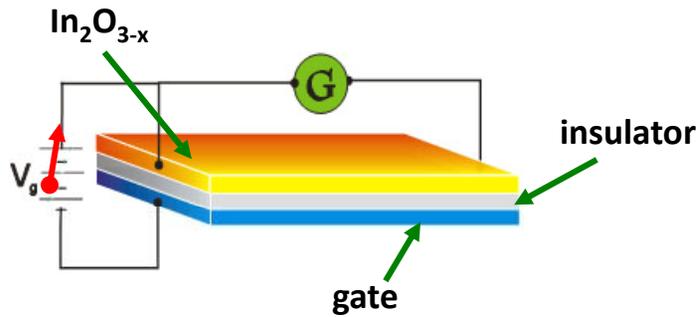
for small  $\delta V_g$ ;  
 $\delta E_F / E_F \ll 1$   
 $D \approx \text{constant}$

$$G \propto \frac{\partial n}{\partial \mu}(E)$$

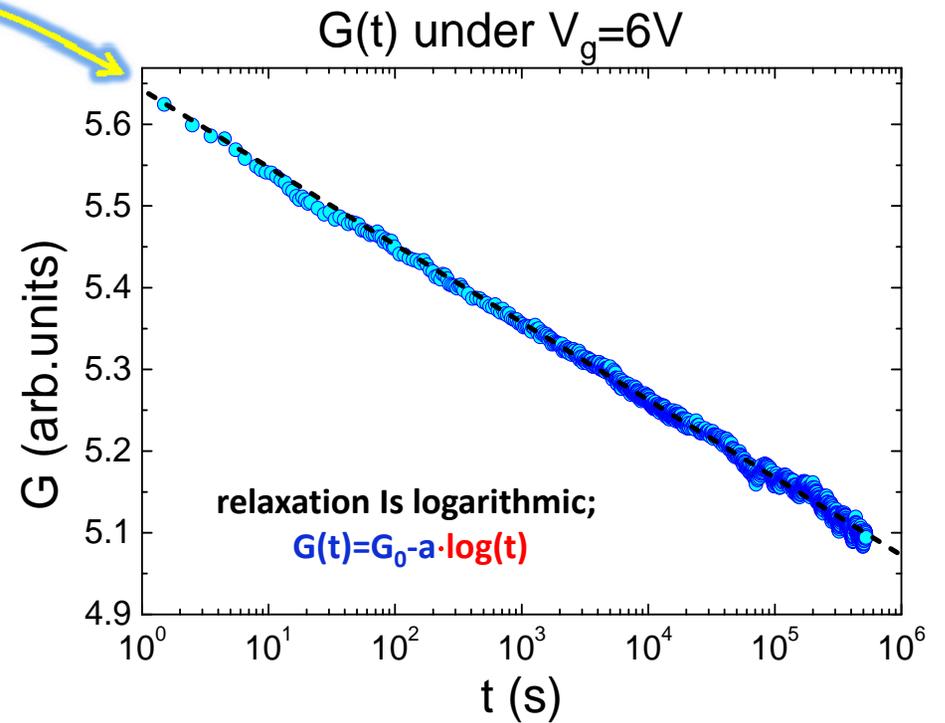
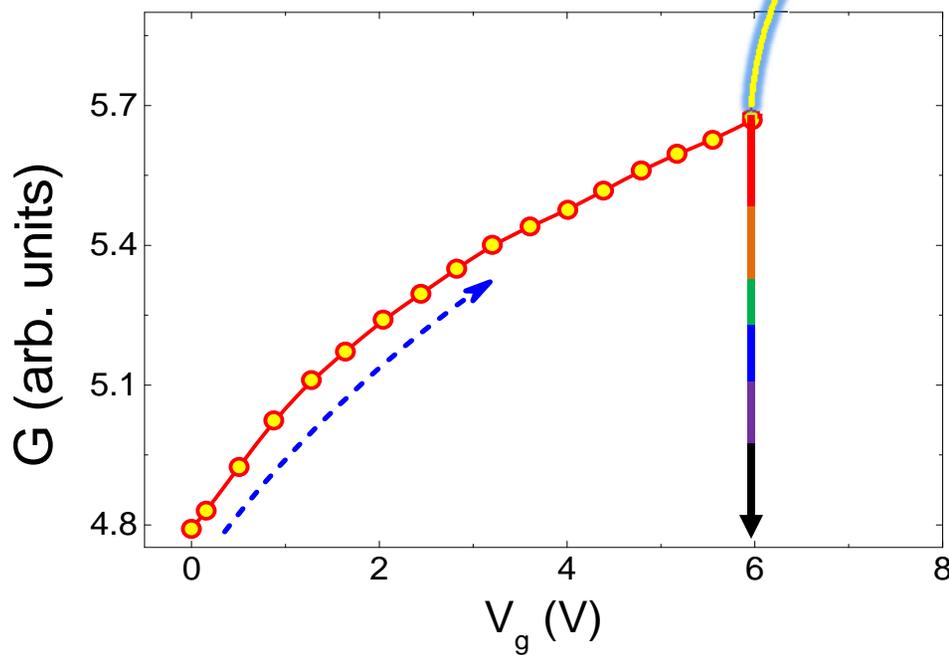
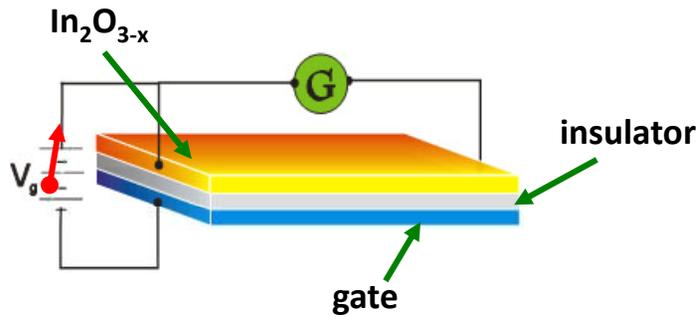


...in the **diffusive** regime...

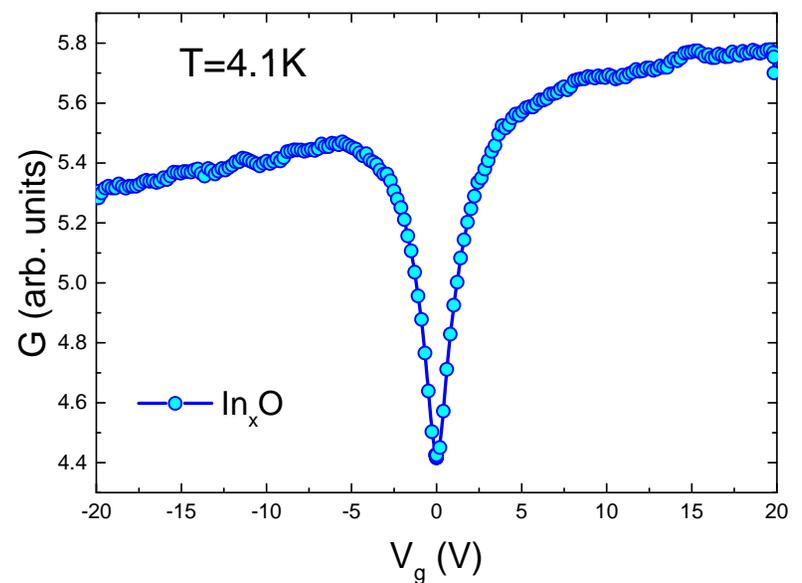
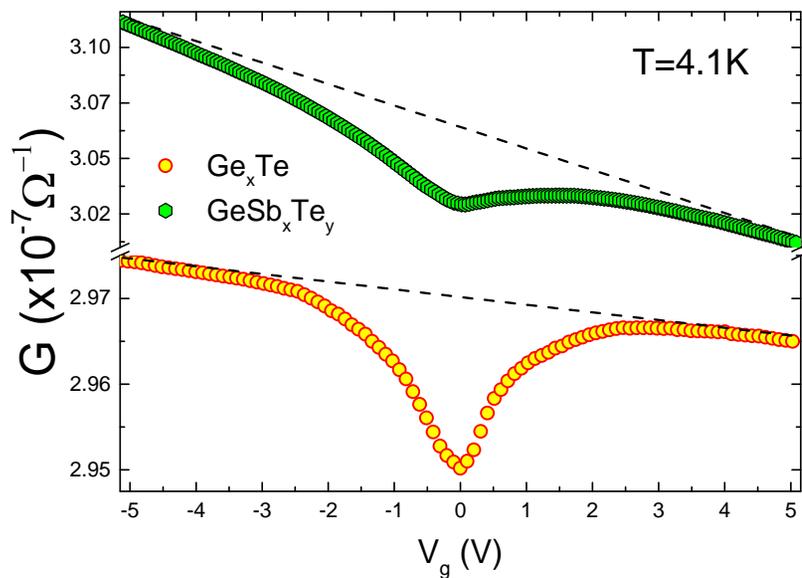
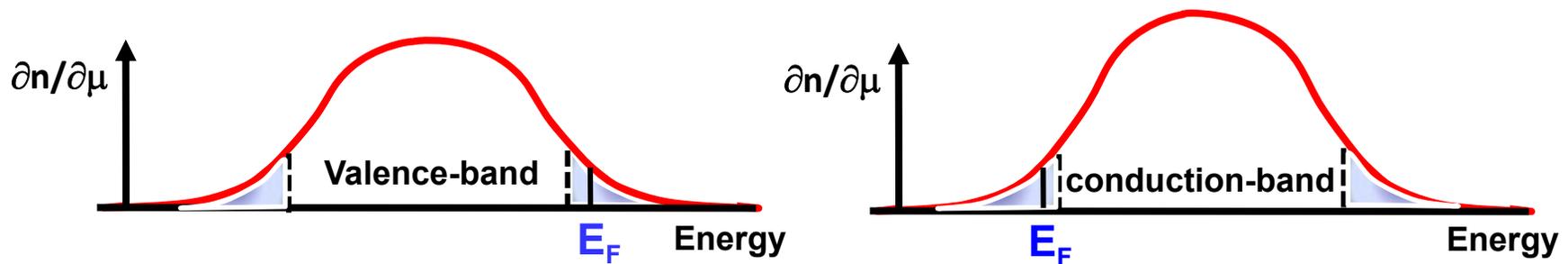
# ...for Anderson insulators:



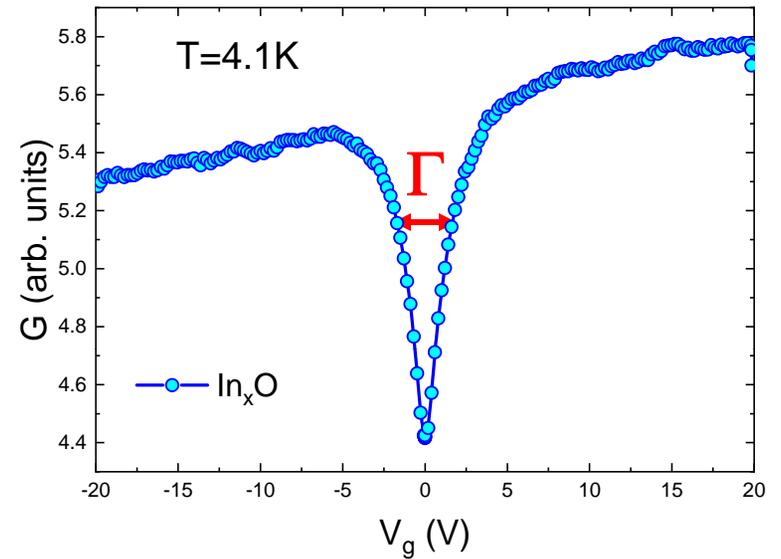
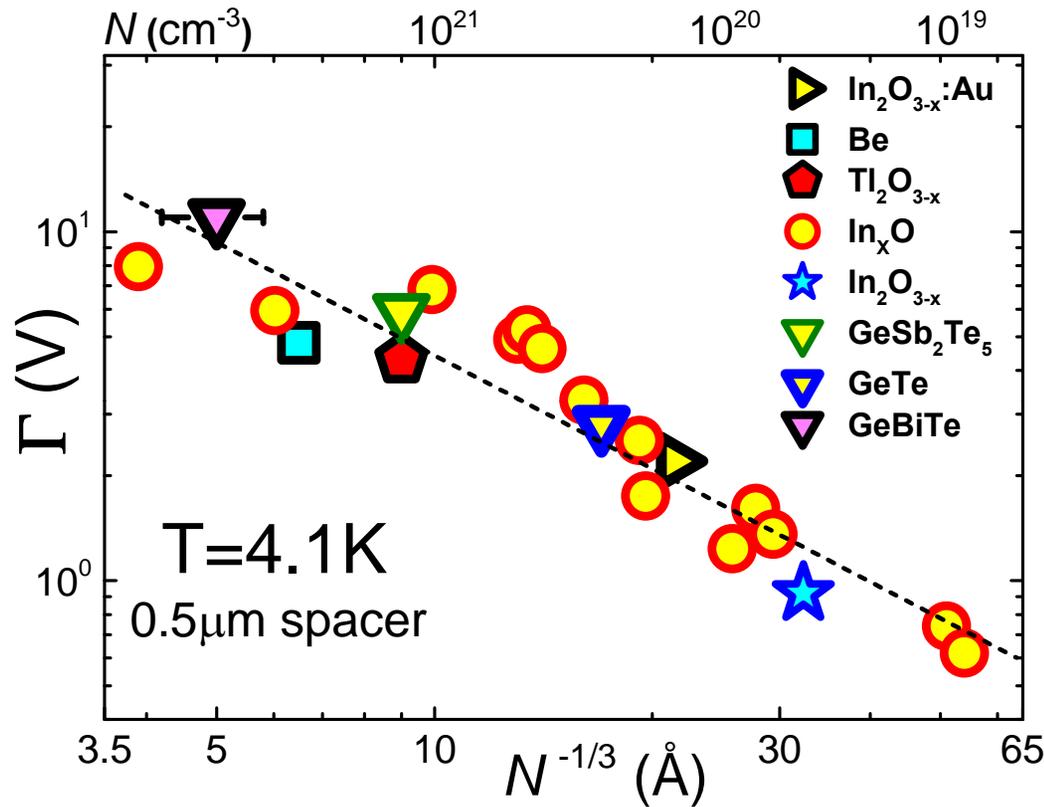
# ...for Anderson insulators:



# ...conditions for observability: Strong-localization



# ...conditions for observability:

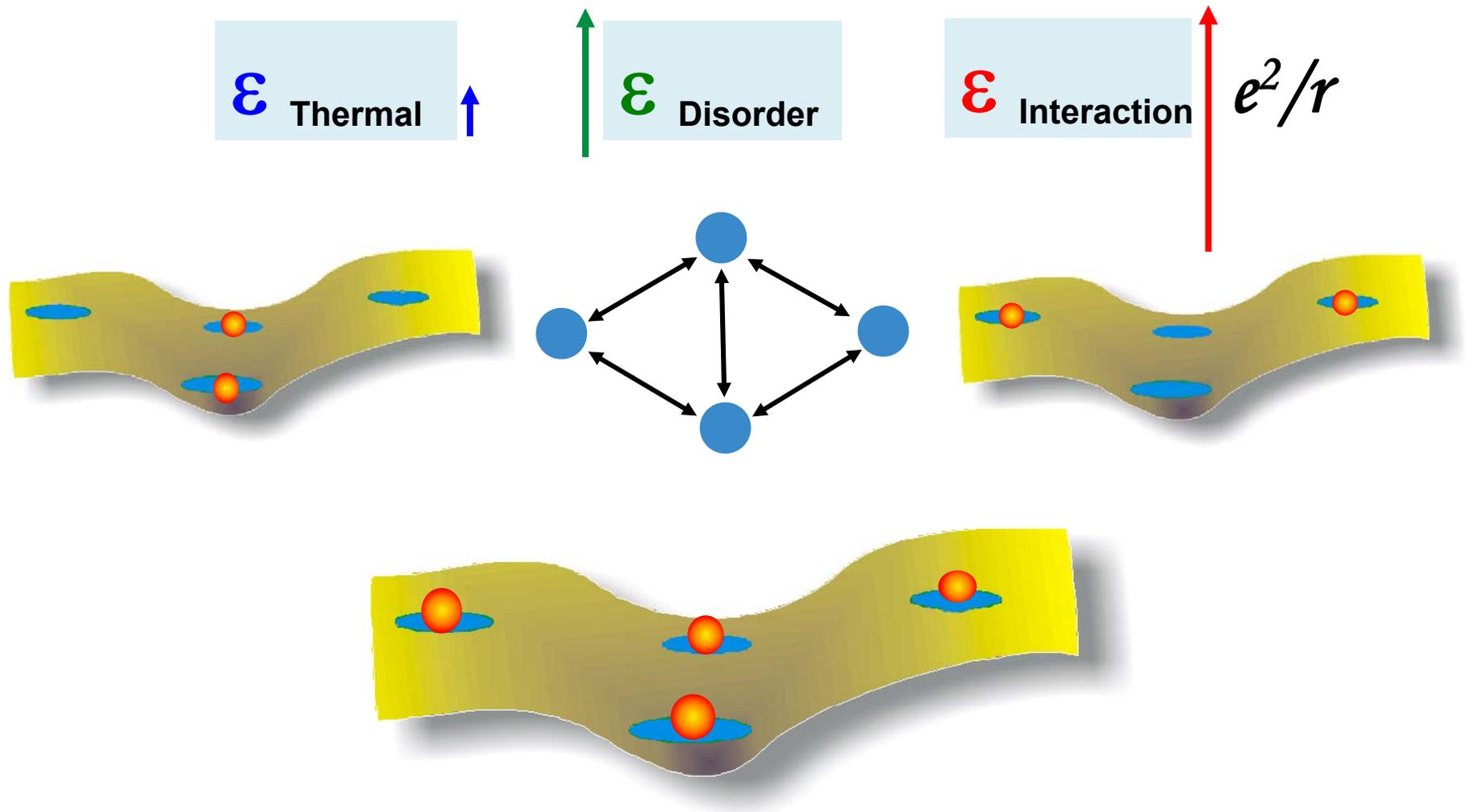


Si, GaAs

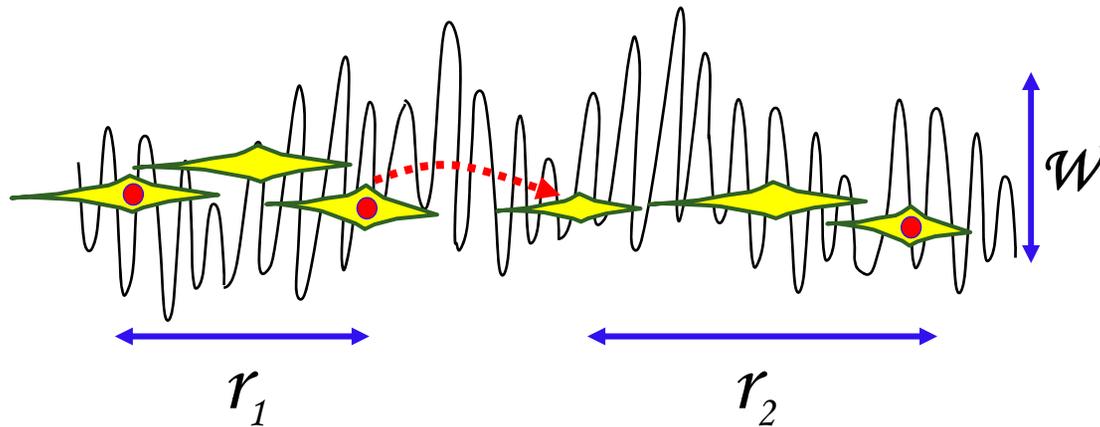


**Carrier-Concentration  $\gg 10^{18}\text{cm}^{-3}$**

# ...e-e interaction slows relaxation...



# ...Disorder slows relaxation...



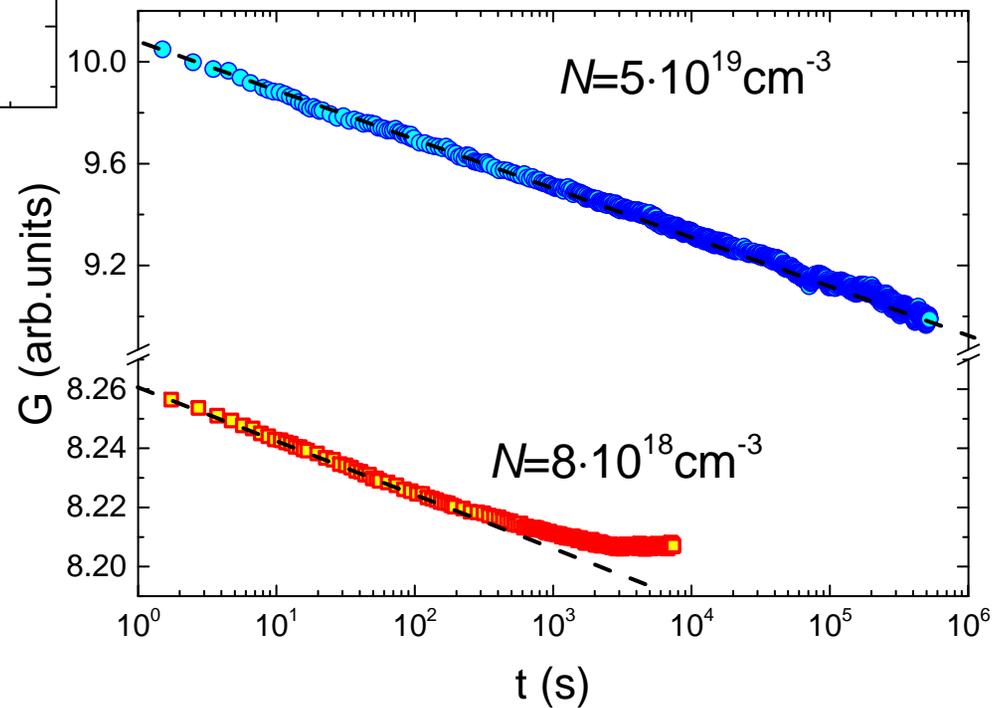
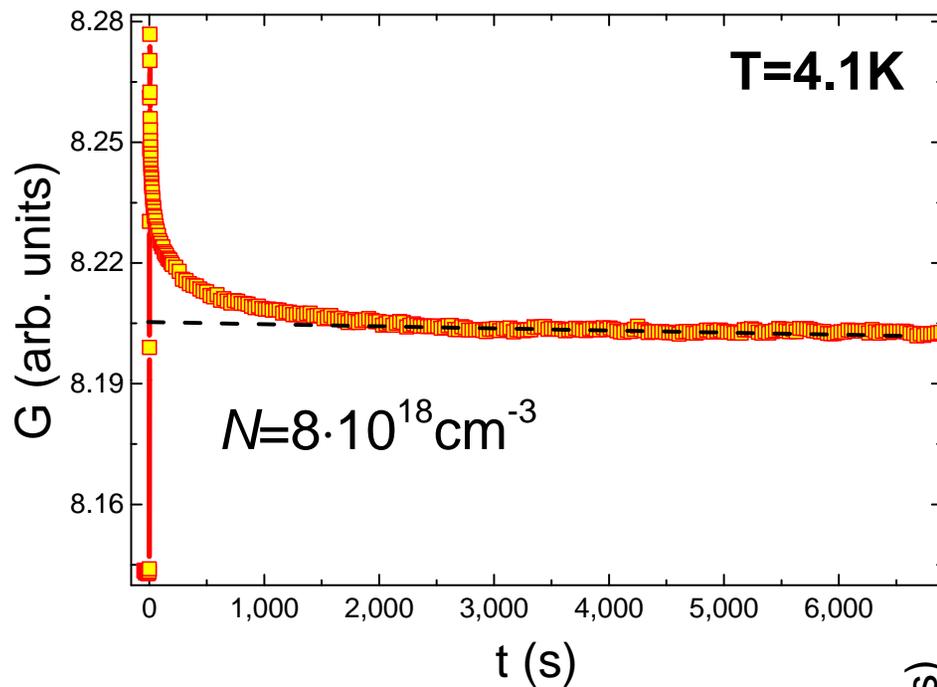
Transition probability  $\propto \exp[-W]$

**Disorder:**  $W \propto E_F \propto \mathcal{N}^{2/3}$        $\mathcal{N}$  = carrier-concentration

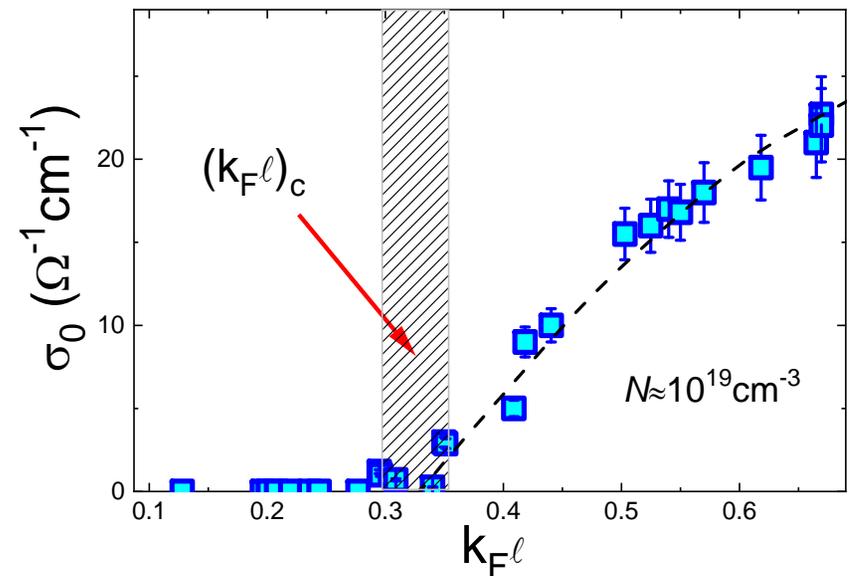
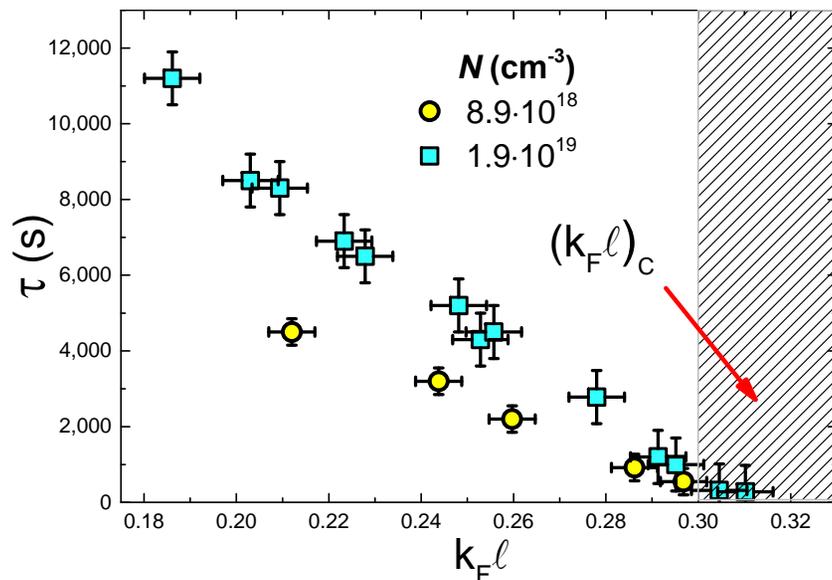
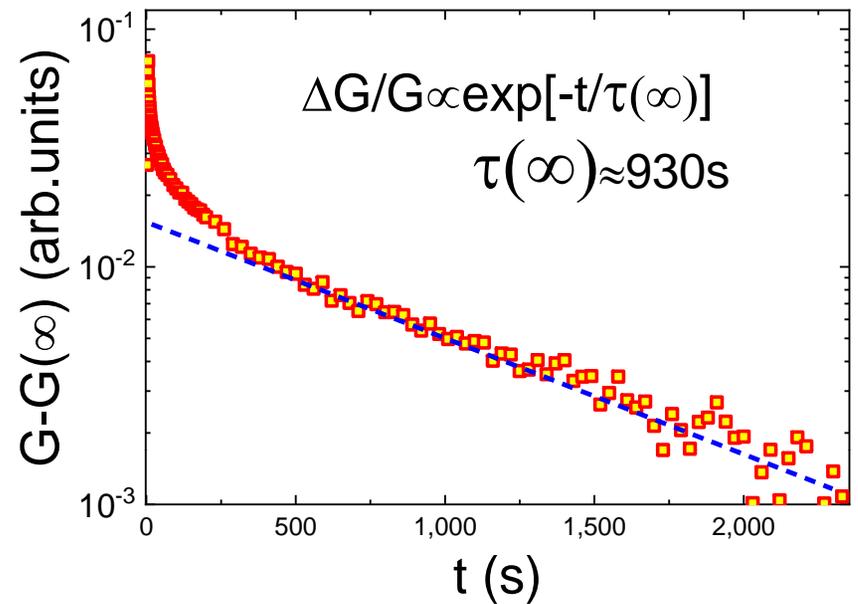
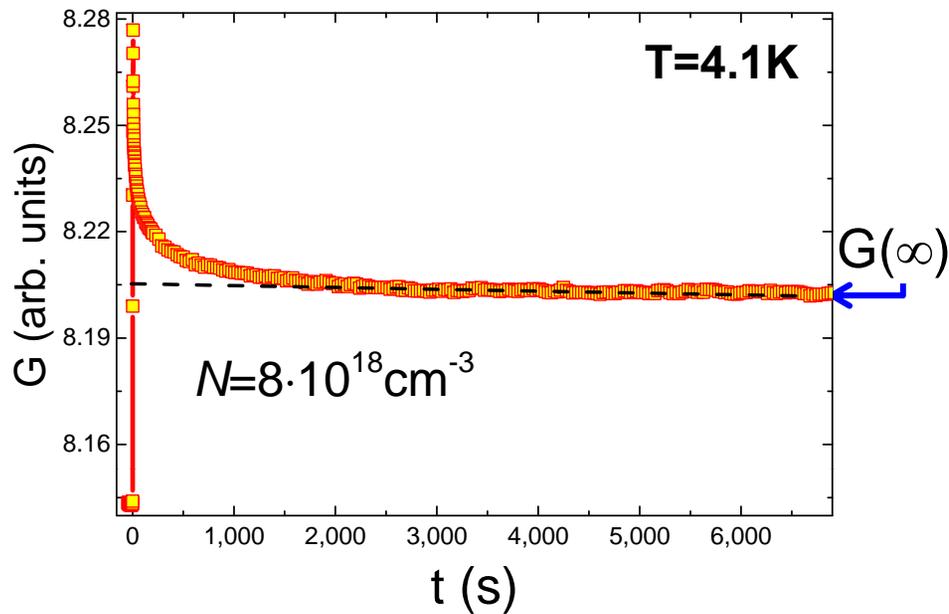
**Interaction:**  $E_C \approx e^2/r \propto \mathcal{N}^{1/3}$

**small  $\mathcal{N}$  (GaAs, Si) – fast dynamics...**

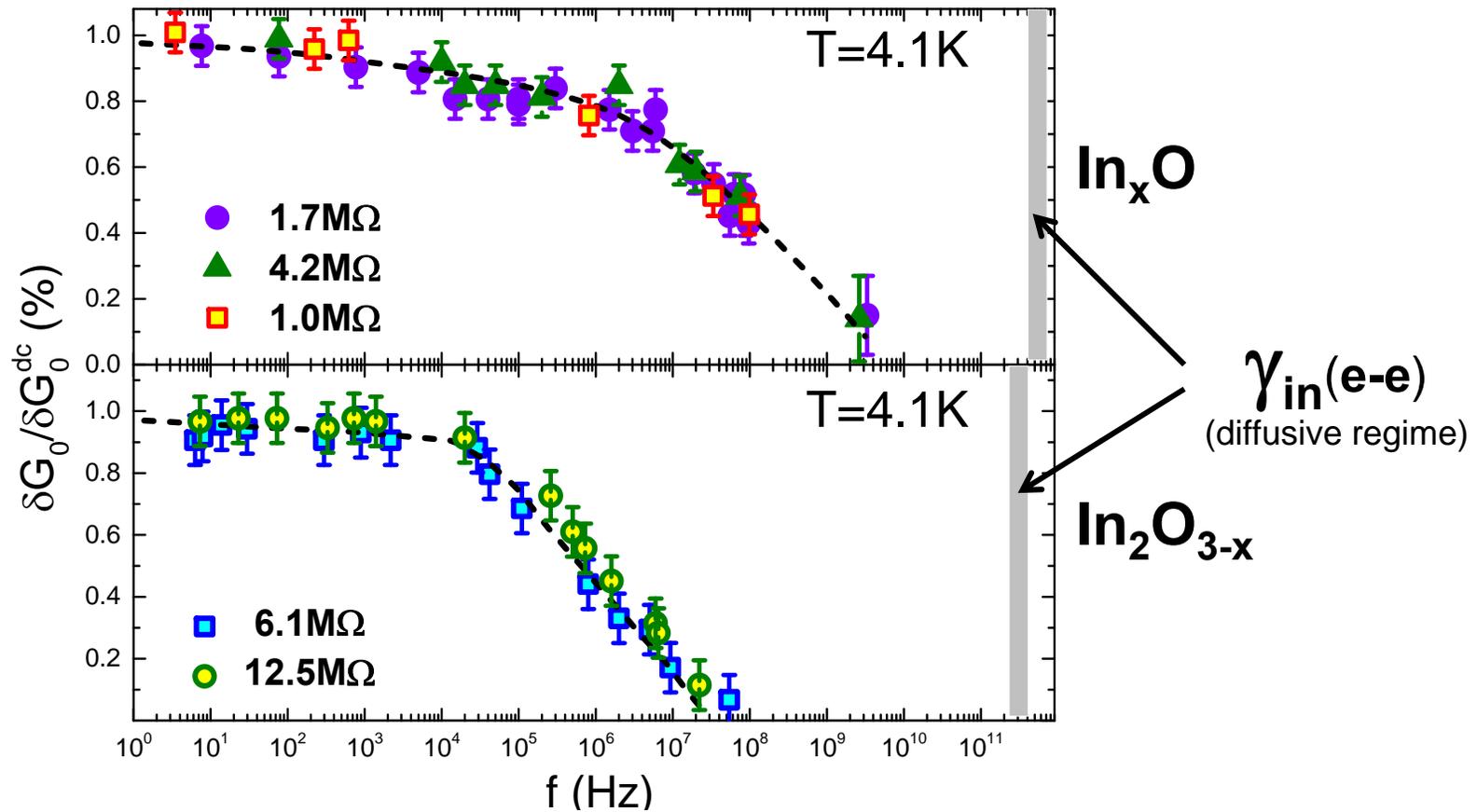
# ...taking $\mathcal{N}$ to the edge...



# ...the end of slow relaxation...

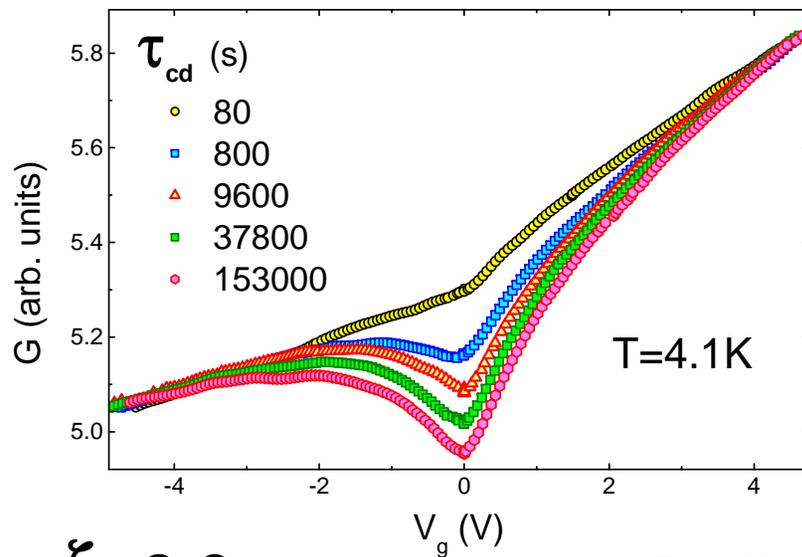
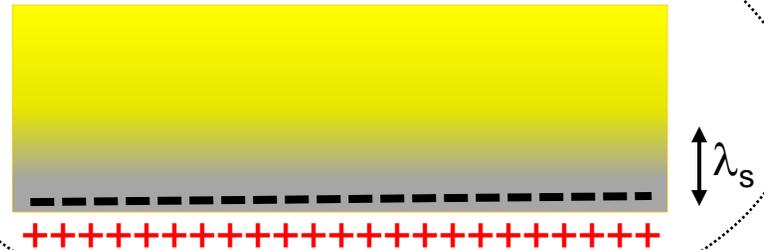
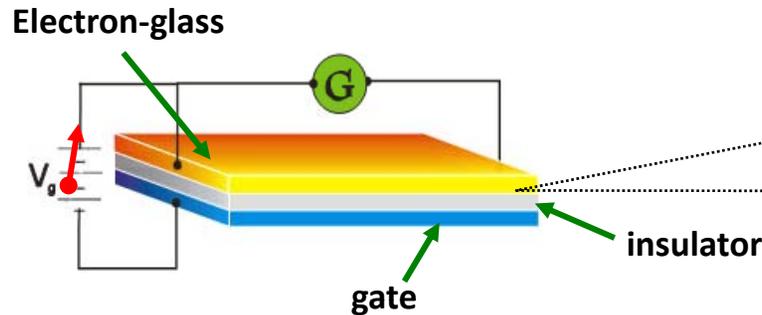


# ...energy absorption of Anderson-insulators



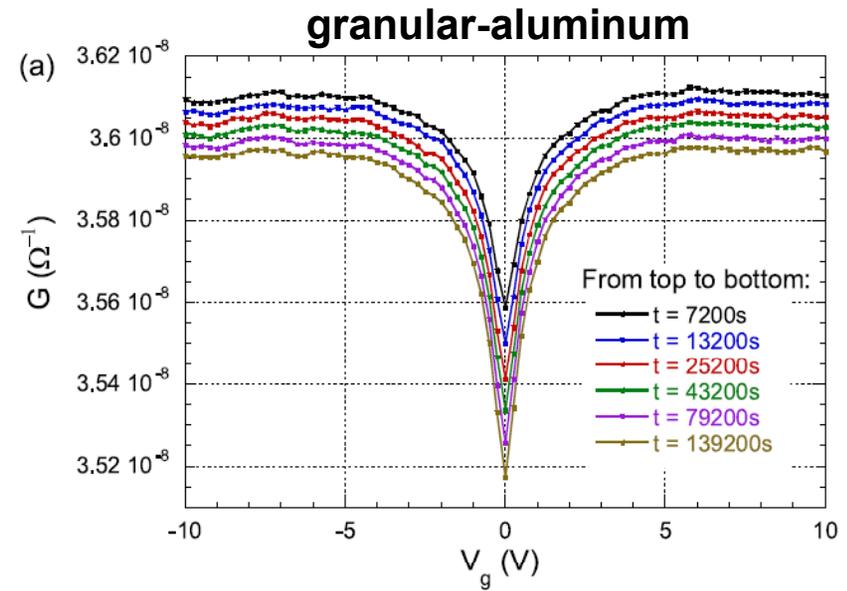
...e-e inelastic scattering is suppressed  
Conductivity is due to phonons...

# ...evolution after a quantum-quench..



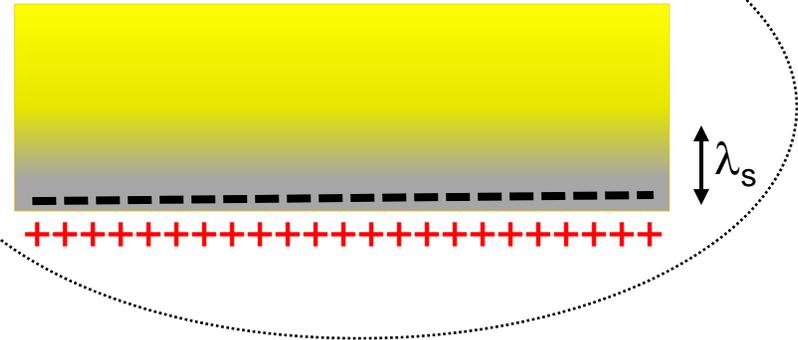
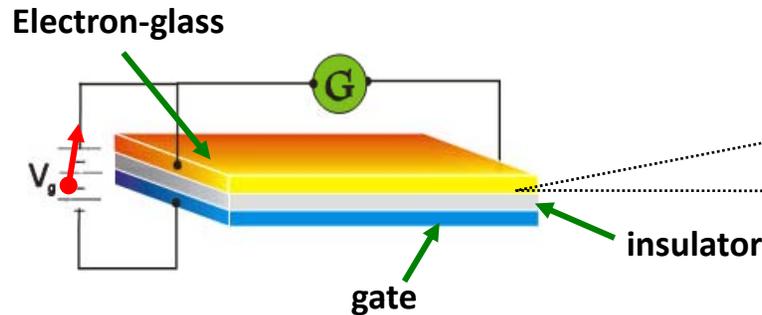
$\xi=2-3nm$

$\tau_{cd}$  = time from cool-down  
...films are  $\approx 10$  nm thick...

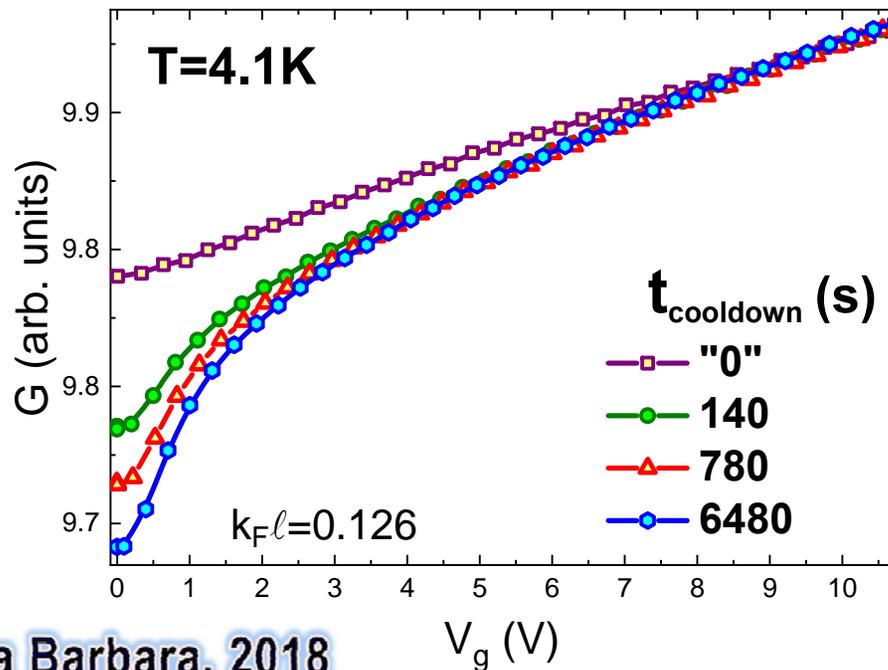


“ $\xi$ ”  $\approx 5nm$

# ...long-range influence; non-locality...



75 nm thick  $\gg \xi$



## ...resonances ?

*Khemani , Nandkishore and Sondhi*  
for Anderson-insulator:

$$r_{\text{ZD}} \propto \ln(Wt^*/\hbar)$$

# Summary

- The electron-glass  $\equiv$  Anderson-insulator
- Both **I**nteraction & **D**isorder play a role

$$E_c \propto \mathcal{N}^{1/3} \quad W \propto \mathcal{N}^{2/3}$$

$$W/E_c \approx 5-50$$